

RELIABILITY REPORT
FOR
MAX1542ETP+
(MAX1542/MAX1543)
PLASTIC ENCAPSULATED DEVICES

February 9, 2009

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.
SUNNYVALE, CA 94086

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| Approved by |
| Ken Wendel |
| Quality Assurance |
| Director, Reliability Engineering |

Conclusion

The MAX1542ETP+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX1542/MAX1543 include a high-performance boost regulator and two high-current operational amplifiers for active matrix, thin-film transistor (TFT), liquid-crystal displays (LCDs). Also included is a logic-controlled, high-voltage switch with adjustable delay. The MAX1543 includes an additional high-voltage load switch and features pin-selectable boost regulator switching frequency. The step-up DC-to-DC converter is a high-frequency 640kHz (MAX1543)/1.2MHz (MAX1542/MAX1543) current-mode regulator with a built-in power MOSFET that allows the use of ultra-small inductors and ceramic capacitors. It provides fast transient response to pulsed loads while producing efficiencies over 85%. The two easy-to-use, high-performance operational amplifiers can drive the LCD backplane (VCOM) and/or the gamma correction divider string. The devices feature high short-circuit current (150mA), fast slew rate (7.5V/ μ s), wide bandwidth (12MHz), and rail-to-rail inputs and outputs. The MAX1542/MAX1543 are available in 20-pin thin QFN packages with a maximum thickness of 0.8mm for ultra-thin LCD panel design.

II. Manufacturing Information

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|----------------------------------|--|
| A. Description/Function: | TFT LCD DC-to-DC Converter with Operational Amplifiers |
| B. Process: | B8 |
| C. Number of Device Transistors: | |
| D. Fabrication Location: | Texas |
| E. Assembly Location: | ASAT China, UTL Thailand |
| F. Date of Initial Production: | January 25, 2003 |

III. Packaging Information

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|--|--------------------------|
| A. Package Type: | 20-pin TQFN 5x5 |
| B. Lead Frame: | Copper |
| C. Lead Finish: | 100% matte Tin |
| D. Die Attach: | Conductive Epoxy |
| E. Bondwire: | Gold (1 mil dia.) |
| F. Mold Material: | Epoxy with silica filler |
| G. Assembly Diagram: | #05-9000-1442 |
| H. Flammability Rating: | Class UL94-V0 |
| I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C | Level 1 |
| J. Single Layer Theta Ja: | 48°C/W |
| K. Single Layer Theta Jc: | 2.1°C/W |
| L. Multi Layer Theta Ja: | 30°C/W |
| M. Multi Layer Theta Jc: | 2.1°C/W |

IV. Die Information

| | |
|----------------------------|---|
| A. Dimensions: | 88 X 106 mils |
| B. Passivation: | Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide) |
| C. Interconnect: | Aluminum/Si (Si = 1%) |
| D. Backside Metallization: | None |
| E. Minimum Metal Width: | 0.8 microns (as drawn) |
| F. Minimum Metal Spacing: | 0.8 microns (as drawn) |
| G. Bondpad Dimensions: | 5 mil. Sq. |
| H. Isolation Dielectric: | SiO ₂ |
| I. Die Separation Method: | Wafer Saw |

V. Quality Assurance Information

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|-----------------------------------|---|
| A. Quality Assurance Contacts: | Ken Wendel (Director, Reliability Engineering) Bryan Preeshl (Managing Director of QA) |
| B. Outgoing Inspection Level: | 0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects. |
| C. Observed Outgoing Defect Rate: | < 50 ppm |
| D. Sampling Plan: | Mil-Std-105D |

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 144 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 7.5 \times 10^{-9}$$

$\lambda = 7.5$ F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly 1000 hour life test monitors on its processes. This data is published in the Product Reliability Report found at <http://www.maxim-ic.com/>. Current monitor data for the B8 Process results in a FIT Rate of 2.71 @ 25C and 17.30 @ 55C (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

C. E.S.D. and Latch-Up Testing

The PD34 die type has been found to have all pins able to withstand a HBM transient pulse of +/-1000 V per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-250 mA.

Table 1
Reliability Evaluation Test Results

MAX1542ETP+

| TEST ITEM | TEST CONDITION | FAILURE IDENTIFICATION | SAMPLE SIZE | NUMBER OF FAILURES |
|---|--|----------------------------------|-------------|--------------------|
| Static Life Test (Note 1) | Ta = 135°C Biased Time = 192 hrs. | DC Parameters & functionality | 144 | 0 |
| Moisture Testing (Note 2) 85/85 | Ta = 85°C RH = 85% Biased Time = 1000hrs. | DC Parameters & functionality | 77 | 0 |
| Mechanical Stress (Note 2) Temperature Cycle | -65°C/150°C 1000 Cycles Method 1010 | DC Parameters & functionality | 77 | 0 |

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data